74LVC1G175

Single D-type flip-flop with reset; positive-edge trigger

Rev. 03 — 21 May 2007 Product data sheet

1. General description

The 74LVC1G175 is a low-power, low-voltage single positive edge triggered D-type flip-flop with individual data (D) input, clock (CP) input, master reset ($\overline{MR}$) input, and Q output.

The master reset ($\overline{MR}$) is an asynchronous active LOW input and operates independently of the clock input. Information on the data input is transferred to the Q output on the LOW-to-HIGH transition of the clock pulse. The D input must be stable one set-up time prior to the LOW-to-HIGH clock transition for predictable operation.

The inputs can be driven from either 3.3 V or 5 V devices. This feature allows the use of this device in a mixed 3.3 V and 5 V environment.

This device is fully specified for partial power-down applications using I_{OFF}. The I_{OFF} circuitry disables the output, preventing the damaging backflow current through the device when it is powered down.

Schmitt trigger action at all inputs makes the circuit highly tolerant of slower input rise and fall times.

2. Features

- Wide supply voltage range from 1.65 V to 5.5 V
- 5 V tolerant inputs for interfacing with 5 V logic
- High noise immunity
- Complies with JEDEC standard:
  - JESD8-7 (1.65 V to 1.95 V)
  - JESD8-5 (2.3 V to 2.7 V)
  - JESD8B/JESD36 (2.7 V to 3.6 V).
- ±24 mA output drive (V_{CC} = 3.0 V)
- ESD protection:
  - HBM JESD22-A114E exceeds 2000 V
  - MM JESD22-A115-A exceeds 200 V.
- CMOS low power consumption
- Latch-up performance exceeds 250 mA
- Direct interface with TTL levels
- Inputs accept voltages up to 5 V
- Multiple package options
- Specified from –40 °C to +85 °C and –40 °C to +125 °C.

3. Ordering information

Table 1. Ordering information

Type number	Package			
	Temperature range	Name	Description	Version
74LVC1G175GW	–40 °C to +125 °C	SC-88	plastic surface-mounted package; 6 leads	SOT363
74LVC1G175GV	–40 °C to +125 °C	SC-74	plastic surface-mounted package (TSOP6); 6 leads	SOT457
74LVC1G175GM	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1.45 × 0.5 mm	SOT886
74LVC1G175GF	–40 °C to +125 °C	XSON6	plastic extremely thin small outline package; no leads; 6 terminals; body 1 × 1 × 0.5 mm	SOT891

4. Marking

Table 2. Marking

Type number	Marking code
74LVC1G175GW	YT
74LVC1G175GV	V75
74LVC1G175GM	YT
74LVC1G175GF	YT

5. Functional diagram

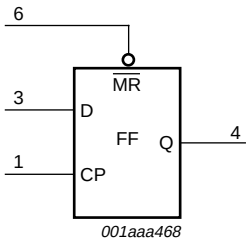


Fig 1. Logic symbol.

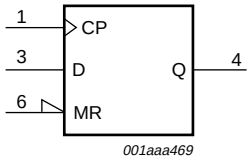


Fig 2. IEC logic symbol.

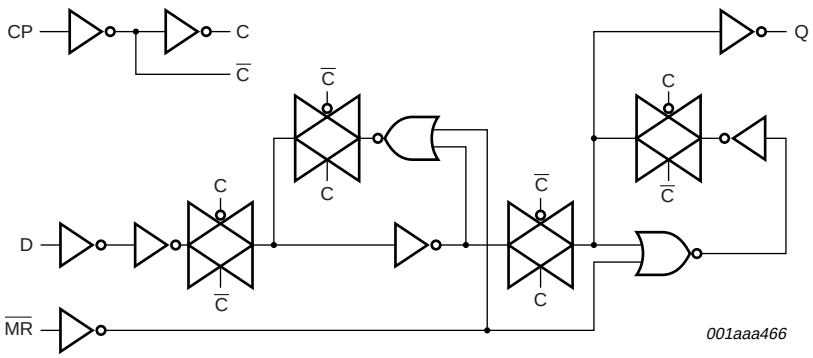


Fig 3. Logic diagram.

6. Pinning information

6.1 Pinning

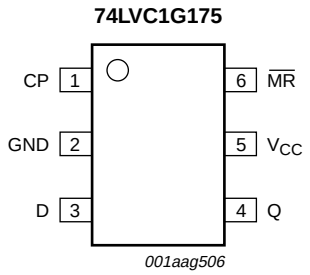
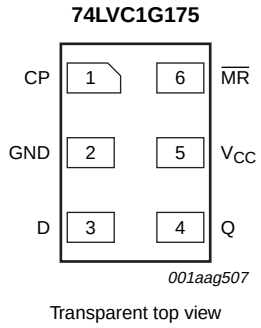
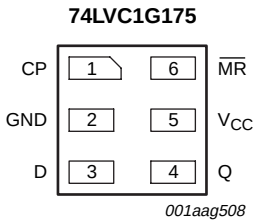


Fig 4. Pin configuration SOT363 and SOT457



Transparent top view

Fig 5. Pin configuration SOT886



Transparent top view

Fig 6. Pin configuration SOT891

6.2 Pin description

Table 3. Pin description

Symbol	Pin	Description
CP	1	clock input (LOW-to-HIGH, edge-triggered)
GND	2	ground (0 V)
D	3	data input
Q	4	flip-flop output
V_{CC}	5	supply voltage
$\overline{MR}$	6	master reset input (active LOW)

7. Functional description

Table 4. Function table[1]

Operating mode	Input			Output
	$\overline{MR}$	CP	D	Q
Reset (clear)	L	X	X	L
Load ‘1’	H	↑	h	H
Load ‘0’	H	↑	l	L

[1] H = HIGH voltage level;
h = HIGH voltage level one set-up time prior to the LOW-to-HIGH CP transition;
L = LOW voltage level;
l = LOW voltage level one set-up time prior to the LOW-to-HIGH CP transition;
↑ = LOW-to-HIGH CP transition;
X = don’t care.

8. Limiting values

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	supply voltage			–0.5	+6.5	V
I_{IK}	input clamping current	$V_I < 0$ V		–50	-	mA
V_I	input voltage		[1]	–0.5	+6.5	V
I_{OK}	output clamping current	$V_O > V_{CC}$ or $V_O < 0$ V		-	±50	mA
V_O	output voltage	Active mode	[1][2]	–0.5	V_{CC} + 0.5	V
		Power-down mode	[1][2]	–0.5	+6.5	V
I_O	output current	V_O = 0 V to V_{CC}		-	±50	mA
I_{CC}	supply current			-	100	mA
I_{GND}	ground current			–100	-	mA
P_{tot}	total power dissipation	T_{amb} = –40 °C to +125 °C	[3]	-	250	mW
T_{stg}	storage temperature			–65	+150	°C

[1] The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

[2] When V_{CC} = 0 V (Power-down mode), the output voltage can be 5.5 V in normal operation.

[3] For SC-88 and SC-74A packages: above 87.5 °C the value of P_{tot} derates linearly with 4.0 mW/K.
For XSON6 packages: above 45 °C the value of P_{tot} derates linearly with 2.4 mW/K.

9. Recommended operating conditions

Table 6. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{CC}	supply voltage		1.65	-	5.5	V
V_I	input voltage		0	-	5.5	V
V_O	output voltage	Active mode	0	-	V_{CC}	V
		Power-down mode; V_{CC} = 0 V	0	-	5.5	V
T_{amb}	ambient temperature		–40	-	+125	°C
$\Delta t/\Delta V$	input transition rise and fall rate	V_{CC} = 1.65 V to 2.7 V	-	-	20	ns/V
		V_{CC} = 2.7 V to 5.5 V	-	-	10	ns/V

10. Static characteristics

Table 7. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		Min	Typ	Max	Unit
T_{amb} = −40 °C to +85 °C	[1]						
V_{IH}	HIGH-level input voltage	V_{CC} = 1.65 V to 1.95 V		0.65 × V_{CC}	-	-	V
		V_{CC} = 2.3 V to 2.7 V		1.7	-	-	V
		V_{CC} = 2.7 V to 3.6 V		2.0	-	-	V
		V_{CC} = 4.5 V to 5.5 V		0.7 × V_{CC}	-	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 1.65 V to 1.95 V		-	-	0.35 × V_{CC}	V
		V_{CC} = 2.3 V to 2.7 V		-	-	0.7	V
		V_{CC} = 2.7 V to 3.6 V		-	-	0.8	V
		V_{CC} = 4.5 V to 5.5 V		-	-	0.3 × V_{CC}	V
V_{OH}	HIGH-level output voltage	V_I = V_{IH} or V_{IL}					
		I_O = −100 µA; V_{CC} = 1.65 V to 5.5 V		V_{CC} − 0.1	-	-	V
		I_O = −4 mA; V_{CC} = 1.65 V		1.2	1.54	-	V
		I_O = −8 mA; V_{CC} = 2.3 V		1.9	2.15	-	V
		I_O = −12 mA; V_{CC} = 2.7 V		2.2	2.50	-	V
		I_O = −24 mA; V_{CC} = 3.0 V		2.3	2.62	-	V
		I_O = −32 mA; V_{CC} = 4.5 V		3.8	4.11	-	V
V_{OL}	LOW-level output voltage	V_I = V_{IH} or V_{IL}					
		I_O = 100 µA; V_{CC} = 1.65 V to 5.5 V		-	-	0.10	V
		I_O = 4 mA; V_{CC} = 1.65 V		-	0.07	0.45	V
		I_O = 8 mA; V_{CC} = 2.3 V		-	0.12	0.30	V
		I_O = 12 mA; V_{CC} = 2.7 V		-	0.17	0.40	V
		I_O = 24 mA; V_{CC} = 3.0 V		-	0.33	0.55	V
		I_O = 32 mA; V_{CC} = 4.5 V		-	0.39	0.55	V
I_I	input leakage current	V_{CC} = 0 V to 5.5 V; V_I = 5.5 V or GND	[2]	-	±0.1	±5	µA
I_{OFF}	power-off leakage current	V_{CC} = 0 V; V_I or V_O = 5.5 V		-	±0.1	±10	µA
I_{CC}	supply current	V_{CC} = 1.65 V to 5.5 V; I_O = 0 A; V_I = 5.5 V or GND		-	0.1	10	µA
ΔI_{CC}	additional supply current	V_{CC} = 2.3 V to 5.5 V; V_I = V_{CC} − 0.6 V; I_O = 0 A	[2]	-	5	500	µA
C_I	input capacitance	V_{CC} = 3.3 V; V_I = GND to V_{CC}		-	2.5	-	pF

Table 7. Static characteristics *…continued*

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
T_{amb} = −40 °C to +125 °C						
V_{IH}	HIGH-level input voltage	V_{CC} = 1.65 V to 1.95 V	0.65 × V_{CC}	-	-	V
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	V
		V_{CC} = 2.7 V to 3.6 V	2.0	-	-	V
		V_{CC} = 4.5 V to 5.5 V	0.7 × V_{CC}	-	-	V
V_{IL}	LOW-level input voltage	V_{CC} = 1.65 V to 1.95 V	-	-	0.35 × V_{CC}	V
		V_{CC} = 2.3 V to 2.7 V	-	-	0.7	V
		V_{CC} = 2.7 V to 3.6 V	-	-	0.8	V
		V_{CC} = 4.5 V to 5.5 V	-	-	0.3 × V_{CC}	V
V_{OH}	HIGH-level output voltage	V_I = V_{IH} or V_{IL}				
		I_O = −100 µA; V_{CC} = 1.65 V to 5.5 V	V_{CC} − 0.1	-	-	V
		I_O = −4 mA; V_{CC} = 1.65 V	0.95	-	-	V
		I_O = −8 mA; V_{CC} = 2.3 V	1.7	-	-	V
		I_O = −12 mA; V_{CC} = 2.7 V	1.9	-	-	V
		I_O = −24 mA; V_{CC} = 3.0 V	2.0	-	-	V
		I_O = −32 mA; V_{CC} = 4.5 V	3.4	-	-	V
V_{OL}	LOW-level output voltage	V_I = V_{IH} or V_{IL}				
		I_O = 100 µA; V_{CC} = 1.65 V to 5.5 V	-	-	0.10	V
		I_O = 4 mA; V_{CC} = 1.65 V	-	-	0.70	V
		I_O = 8 mA; V_{CC} = 2.3 V	-	-	0.45	V
		I_O = 12 mA; V_{CC} = 2.7 V	-	-	0.60	V
		I_O = 24 mA; V_{CC} = 3.0 V	-	-	0.80	V
		I_O = 32 mA; V_{CC} = 4.5 V	-	-	0.80	V
I_I	input leakage current	V_{CC} = 0 V to 5.5 V; V_I = 5.5 V or GND	-	-	±20	µA
I_{OFF}	power-off leakage current	V_{CC} = 0 V; V_I or V_O = 5.5 V	-	-	±20	µA
I_{CC}	supply current	V_{CC} = 1.65 V to 5.5 V; I_O = 0 A; V_I = 5.5 V or GND	-	-	40	µA
ΔI_{CC}	additional supply current	V_{CC} = 2.3 V to 5.5 V; V_I = V_{CC} − 0.6 V; I_O = 0 A	-	-	5000	µA

[1] All typical values are measured at T_{amb} = 25 °C.

[2] These typical values are measured at V_{CC} = 3.3 V.

11. Dynamic characteristics

Table 8. Dynamic characteristics

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9.

Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
t_{pd}	propagation delay	CP to Q; see Figure 7						
		V_{CC} = 1.65 V to 1.95 V	1.5	4.9	13.4	1.5	17	ns
		V_{CC} = 2.3 V to 2.7 V	1.0	3.1	7.1	1.0	9.0	ns
		V_{CC} = 2.7 V	1.0	3.2	7.1	1.0	9.0	ns
		V_{CC} = 3.0 V to 3.6 V	1.0	3.1	5.7	0.5	7.5	ns
		V_{CC} = 4.5 V to 5.5 V	1.0	2.2	4.0	0.5	5.5	ns
		$\overline{MR}$ to Q; see Figure 8						
		V_{CC} = 1.65 V to 1.95 V	1.5	4.3	12.9	1.5	17	ns
		V_{CC} = 2.3 V to 2.7 V	1.0	2.8	7.0	1.0	9.0	ns
		V_{CC} = 2.7 V	1.0	3.0	7.0	1.0	9.0	ns
		V_{CC} = 3.0 V to 3.6 V	1.0	2.5	5.8	0.5	7.5	ns
		V_{CC} = 4.5 V to 5.5 V	1.0	2.0	4.1	0.5	5.5	ns
t_W	pulse width	CP HIGH or LOW; see Figure 7						
		V_{CC} = 1.65 V to 1.95 V	6.2	-	-	6.2	-	ns
		V_{CC} = 2.3 V to 2.7 V	2.7	-	-	2.7	-	ns
		V_{CC} = 2.7 V	2.7	-	-	2.7	-	ns
		V_{CC} = 3.0 V to 3.6 V	2.7	1.3	-	2.7	-	ns
		V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	ns
		$\overline{MR}$ LOW; see Figure 8						
		V_{CC} = 1.65 V to 1.95 V	6.2	-	-	6.2	-	ns
		V_{CC} = 2.3 V to 2.7 V	2.7	-	-	2.7	-	ns
		V_{CC} = 2.7 V	2.7	-	-	2.7	-	ns
		V_{CC} = 3.0 V to 3.6 V	2.7	1.6	-	2.7	-	ns
		V_{CC} = 4.5 V to 5.5 V	2.0	-	-	2.0	-	ns
t_{rec}	recovery time	$\overline{MR}$; see Figure 8						
		V_{CC} = 1.65 V to 1.95 V	1.9	-	-	1.9	-	ns
		V_{CC} = 2.3 V to 2.7 V	1.4	-	-	1.4	-	ns
		V_{CC} = 2.7 V	1.3	-	-	1.3	-	ns
		V_{CC} = 3.0 V to 3.6 V	1.2	0.4	-	1.2	-	ns
		V_{CC} = 4.5 V to 5.5 V	1.0	-	-	1.0	-	ns
t_{su}	set-up time	D to CP; see Figure 7						
		V_{CC} = 1.65 V to 1.95 V	2.9	-	-	2.9	-	ns
		V_{CC} = 2.3 V to 2.7 V	1.7	-	-	1.7	-	ns
		V_{CC} = 2.7 V	1.7	-	-	1.7	-	ns
		V_{CC} = 3.0 V to 3.6 V	1.3	0.5	-	1.3	-	ns
		V_{CC} = 4.5 V to 5.5 V	1.1	-	-	1.1	-	ns

Table 8. Dynamic characteristics *…continued*

Voltages are referenced to GND (ground = 0 V); for test circuit see Figure 9.

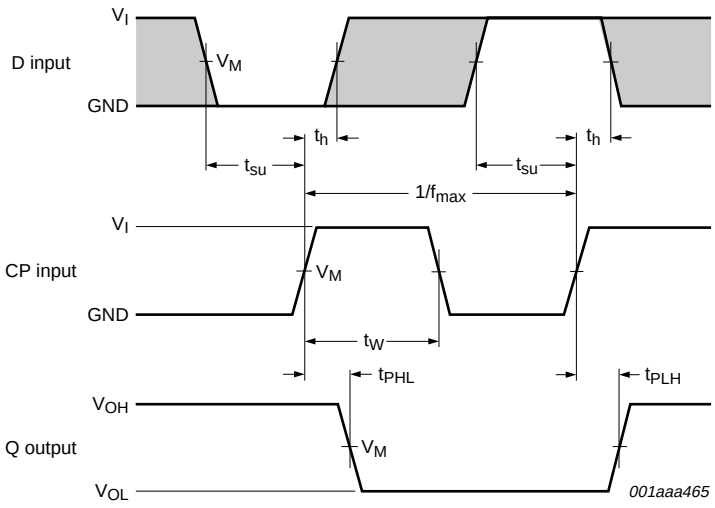
Symbol	Parameter	Conditions	–40 °C to +85 °C			–40 °C to +125 °C		Unit
			Min	Typ[1]	Max	Min	Max	
t_h	hold time	D to CP; see Figure 7						
		V_{CC} = 1.65 V to 1.95 V	0.0	-	-	0.0	-	ns
		V_{CC} = 2.3 V to 2.7 V	0.3	-	-	0.3	-	ns
		V_{CC} = 2.7 V	0.5	-	-	0.5	-	ns
		V_{CC} = 3.0 V to 3.6 V	1.2	0.2	-	1.2	-	ns
		V_{CC} = 4.5 V to 5.5 V	0.5	-	-	0.5	-	ns
f_{max}	maximum frequency	CP; see Figure 7						
		V_{CC} = 1.65 V to 1.95 V	80	125	-	80	-	MHz
		V_{CC} = 2.3 V to 2.7 V	175	-	-	175	-	MHz
		V_{CC} = 2.7 V	175	-	-	175	-	MHz
		V_{CC} = 3.0 V to 3.6 V	175	300	-	175	-	MHz
		V_{CC} = 4.5 V to 5.5 V	200	-	-	200	-	MHz
C_{PD}	power dissipation capacitance	V_I = GND to V_{CC}; V_{CC} = 3.3 V [3]	-	14	-	-	-	pF

[1] Typical values are measured at T_{amb} = 25 °C and V_{CC} = 1.8 V, 2.5 V, 2.7 V, 3.3 V and 5.0 V respectively.

[2] t_{pd} is the same as t_{PLH} and t_{PHL}.

[3] C_{PD} is used to determine the dynamic power dissipation (P_D in µW).
$P_D = C_{PD} \times V_{CC}^2 \times f_i \times N + \Sigma(C_L \times V_{CC}^2 \times f_o)$ where:
f_i = input frequency in MHz;
f_o = output frequency in MHz;
C_L = output load capacitance in pF;
V_{CC} = supply voltage in Volts;
N = number of inputs switching;
$\Sigma(C_L \times V_{CC}^2 \times f_o)$ = sum of the outputs.

12. Waveforms

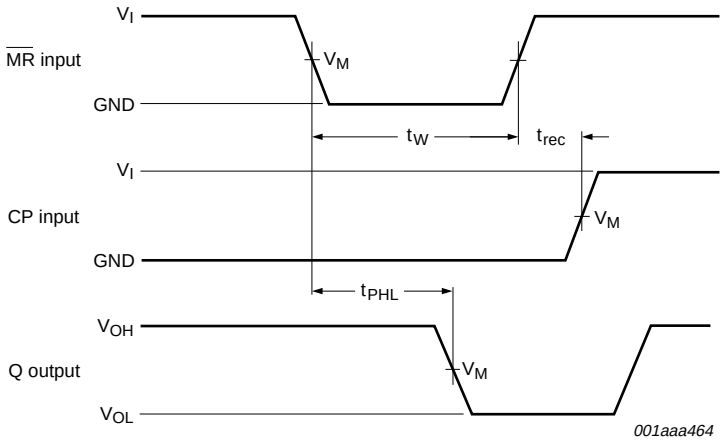


Measurement points are given in Table 9.

The shaded areas indicate when the input is permitted to change for predictable output performance.

V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig 7. The clock input (CP) to output (Q) propagation delays, the clock pulse width, the D to CP set-up, the CP to D hold times, and the maximum clock pulse frequency



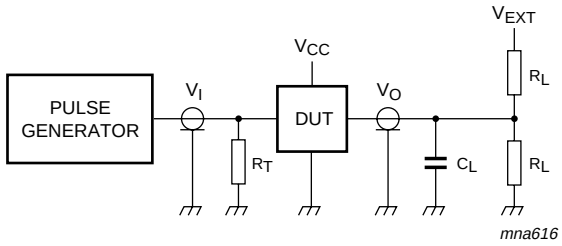
Measurement points are given in Table 9.

V_{OL} and V_{OH} are typical output voltage drops that occur with the output load.

Fig 8. The master reset ($\overline{MR}$) input to output (Q) propagation delays, the master reset pulse width, and the $\overline{MR}$ to CP recovery time

Table 9. Measurement points

Supply voltage	Input	Output
V_{CC}	V_M	V_M
1.65 V to 1.95 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.3 V to 2.7 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$
2.7 V	1.5 V	1.5 V
3.0 V to 3.6 V	1.5 V	1.5 V
4.5 V to 5.5 V	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$



Test data is given in Table 10.

Definitions for test circuit:

R_L = Load resistance.

C_L = Load capacitance including jig and probe capacitance.

R_T = Termination resistance should be equal to the output impedance Z_o of the pulse generator.

V_{EXT} = External voltage for measuring switching times.

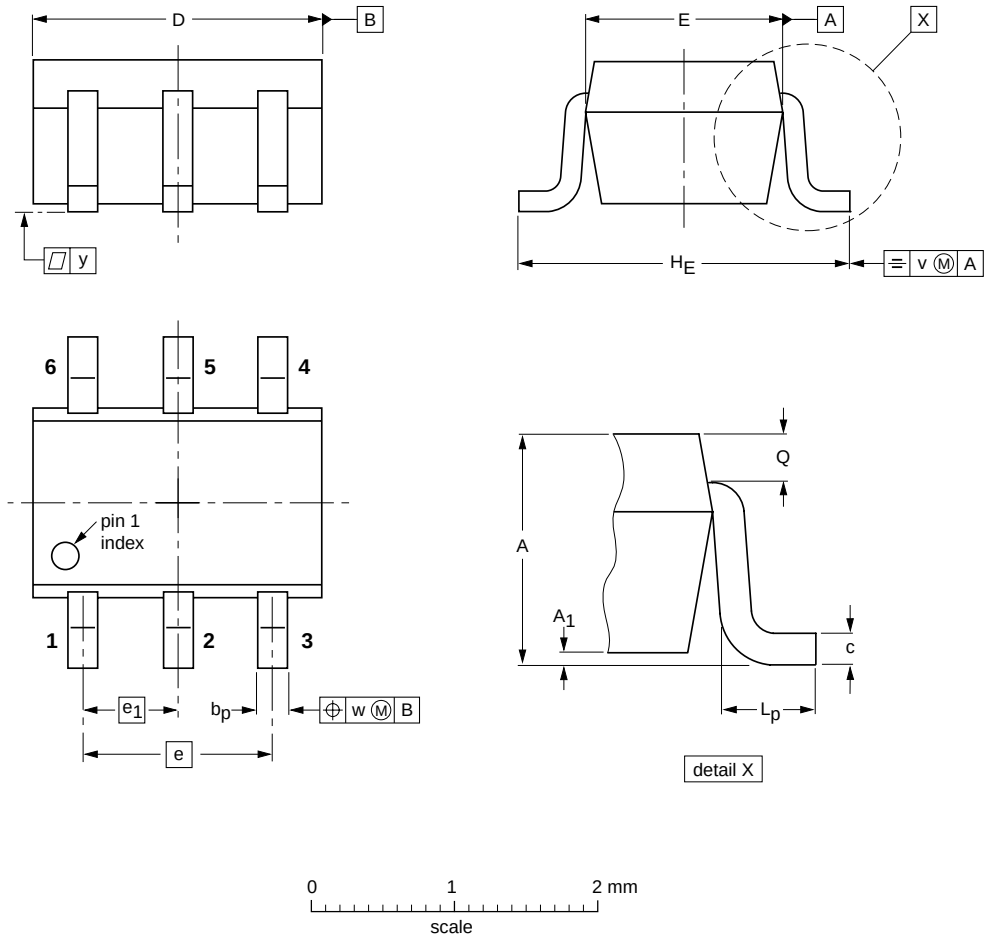
Fig 9. Load circuitry for switching times

Table 10. Test data

Supply voltage	Input		Load		V_{EXT}
V_{CC}	V_I	$t_r = t_f$	C_L	R_L	t_{PLH}, t_{PHL}
1.65 V to 1.95 V	V_{CC}	≤ 2.0 ns	30 pF	1 kΩ	open
2.3 V to 2.7 V	V_{CC}	≤ 2.0 ns	30 pF	500 Ω	open
2.7 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	500 Ω	open
4.5 V to 5.5 V	V_{CC}	≤ 2.5 ns	50 pF	500 Ω	open

13. Package outline

Plastic surface-mounted package; 6 leads **SOT363**



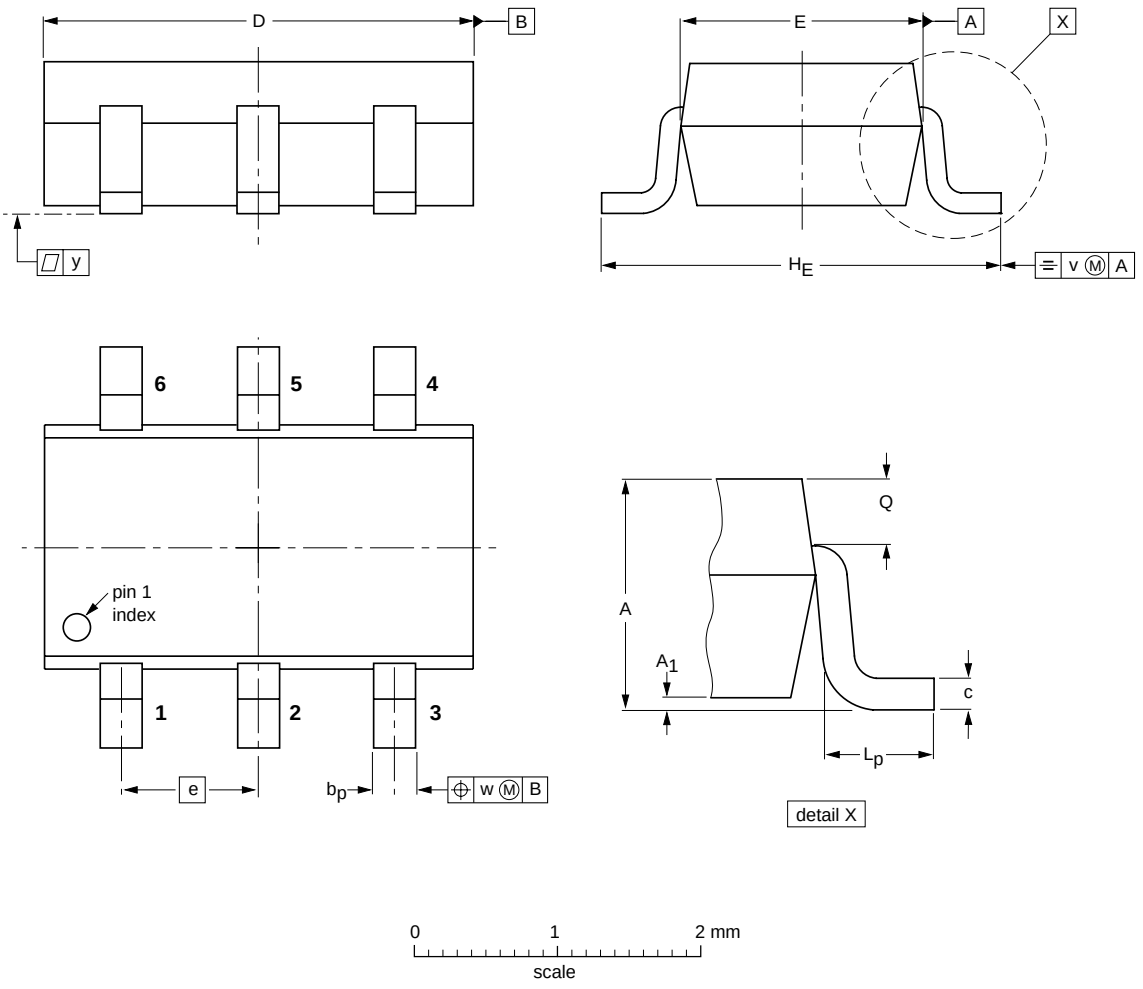
DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1 max	b_p	c	D	E	e	e_1	H_E	L_p	Q	v	w	y
mm	1.1 0.8	0.1	0.30 0.20	0.25 0.10	2.2 1.8	1.35 1.15	1.3	0.65	2.2 2.0	0.45 0.15	0.25 0.15	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT363			SC-88			~~04-11-08~~ 06-03-16

Fig 10. Package outline SOT363 (SC-88)

Plastic surface-mounted package (TSOP6); 6 leads **SOT457**



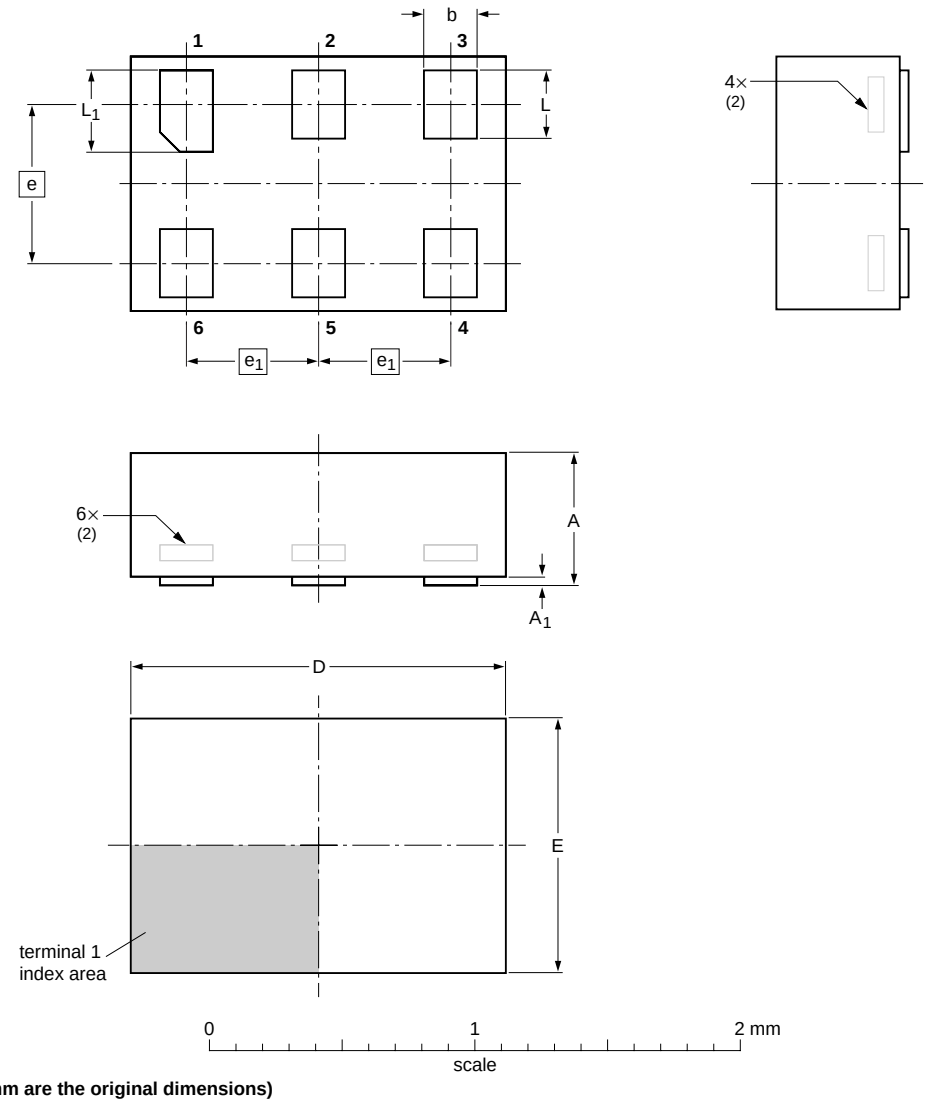
DIMENSIONS (mm are the original dimensions)

UNIT	A	A_1	b_p	c	D	E	e	H_E	L_p	Q	v	w	y
mm	1.1 0.9	0.1 0.013	0.40 0.25	0.26 0.10	3.1 2.7	1.7 1.3	0.95	3.0 2.5	0.6 0.2	0.33 0.23	0.2	0.2	0.1

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT457			SC-74			~~05-11-07~~ 06-03-16

Fig 11. Package outline SOT457 (SC-74)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1.45 x 0.5 mm **SOT886**



DIMENSIONS (mm are the original dimensions)

UNIT	A(1) max	A1 max	b	D	E	e	e1	L	L1
mm	0.5	0.04	0.25 0.17	1.5 1.4	1.05 0.95	0.6	0.5	0.35 0.27	0.40 0.32

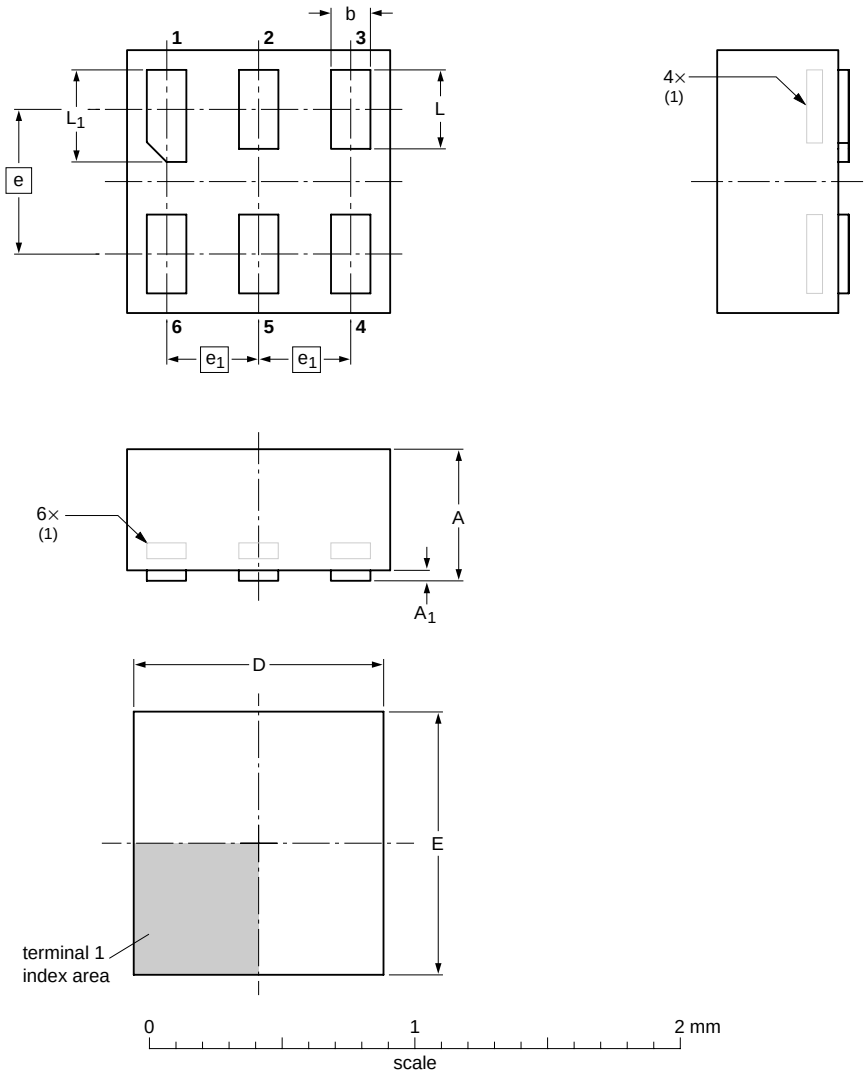
Notes

1. Including plating thickness.
2. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT886		MO-252				~~04-07-15~~ 04-07-22

Fig 12. Package outline SOT886 (XSON6)

XSON6: plastic extremely thin small outline package; no leads; 6 terminals; body 1 x 1 x 0.5 mm **SOT891**



DIMENSIONS (mm are the original dimensions)

UNIT	A max	A_1 max	b	D	E	e	e_1	L	L_1
mm	0.5	0.04	0.20 0.12	1.05 0.95	1.05 0.95	0.55	0.35	0.35 0.27	0.40 0.32

Note

1. Can be visible in some manufacturing processes.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	JEITA			
SOT891						~~05-04-06~~ 07-05-15

Fig 13. Package outline SOT891 (XSON6)

14. Abbreviations

Table 11. Abbreviations

Acronym	Description
CMOS	Complementary Metal Oxide Semiconductor
DUT	Device Under Test
ESD	ElectroStatic Discharge
HBM	Human Body Model
MM	Machine Model
TTL	Transistor-Transistor Logic

15. Revision history

Table 12. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC1G175_3	20070521	Product data sheet	-	74LVC1G175_2
Modifications:	• The format of this data sheet has been redesigned to comply with the new identity guidelines of NXP Semiconductors. • Legal texts have been adapted to the new company name where appropriate. • Added type number 74LVC1G175GF (XSON6/SOT891 package) • Section 10 “Static characteristics”: Changed: Conditions for input leakage and supply current.			
74LVC1G175_2	20041018	Product specification	-	74LVC1G175_1
74LVC1G175_1	20040318	Product specification	-	-

16. Legal information

16.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

[3] The product status of device(s) described in this document may have changed since this document was published and may differ in case of multiple devices. The latest product status information is available on the Internet at URL http://www.nxp.com.

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18. Contents

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